Low-Voltage CMOS 16-Bit Buffer

With 5V-Tolerant Inputs and Outputs (3-State, Inverting)

The MC74LCX16240 is a high performance, inverting 16-bit buffer operating from a 2.3 to 3.6 V supply. The device is nibble controlled. Each nibble has separate Output Enable inputs which can be tied together for full 16-bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A VI specification of 5.5 V allows MC74LCX16240 inputs to be safely driven from 5 V devices. The LCX16240 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

<u>Current drive capability</u> is 24 mA at the outputs. The Output Enable (OEn) inputs, when HIGH, disable the outputs by placing them in a HIGH Z condition.

The MC74LCX16240 contains sixteen inverting buffers with 3–state 5 V–tolerant outputs. The device is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full 16–bit operation. The 3–state outputs are controlled by an Output Enable (OEn) input for each nibble. When OEn is LOW, the outputs are on. When OEn is HIGH, the outputs are in the high impedance state.

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5 V Tolerant Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When V_{CC} = 0 V
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V;
 Machine Model >200 V



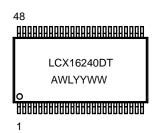
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MARKING DIAGRAM



TSSOP-48 DT SUFFIX CASE 1201-01



A = Assembly Location

WL = Wafer Lot

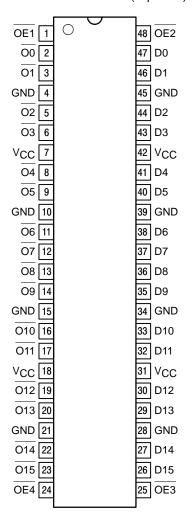
YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC74LCX16240DT	TSSOP-48	39 Units/Rail
MC74LCX16240DTR2	TSSOP-48	2500 Units/Reel

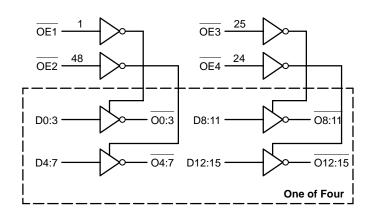
PINOUT: 48-LEAD (Top View)



PIN NAMES

PINS	FUNCTION
OEn	Output Enable Inputs
D0-D15	Inputs
O0-O15	Outputs

LOGIC DIAGRAM



TRUTH TABLE

OE1	D0:3	O0:3	OE2	D4:7	04:7	OE3	D8:11	O8:11	OE4	D12:15	O12:15
L	L	Н	L	L	Н	L	L	Н	L	L	Н
L	Н	L	L	Н	L	L	Н	L	L	Н	L
Н	Х	Z	Н	Х	Z	Н	Х	Z	Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for ICC reasons, DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
Vcc	DC Supply Voltage	-0.5 to +7.0		V
٧ _I	DC Input Voltage	$-0.5 \le V_{\parallel} \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3-State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Output in HIGH or LOW State (Note 1.)	V
lıK	DC Input Diode Current	- 50	V _I < GND	mA
lok	DC Output Diode Current	-50	V _O < GND	mA
		+50	VO > √CC	mA
lo	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Paramete	er	Min	Тур	Max	Unit
VCC	Supply Voltage	Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	3.6 3.6	V
٧ _I	Input Voltage		0		5.5	V
Vo	Output Voltage	(HIGH or LOW State) (3-State)	0 0		V _{CC} 5.5	V
ЮН	HIGH Level Output Current	V _{CC} = 3.0 V - 3.6 V V _{CC} = 2.7 V - 3.0 V V _{CC} = 2.3 V - 2.7 V			- 24 - 12 - 8	mA
l _{OL}	LOW Level Output Current	V _{CC} = 3.0 V - 3.6 V V _{CC} = 2.7 V - 3.0 V V _{CC} = 2.3 V - 2.7 V			+ 24 + 12 + 8	mA
T _A	Operating Free–Air Temperature		-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V_{IN} $V_{CC} = 3.0 \text{ V}$	from 0.8 V to 2.0 V,	0		10	ns/V

^{1.} IO absolute maximum rating must be observed.

DC ELECTRICAL CHARACTERISTICS

			T _A = −40°C		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	2.3 V ≤ V _{CC} ≤ 2.7 V	1.7		V
		2.7 V ≤ V _{CC} ≤ 3.6 V	2.0		
V _{IL}	LOW Level Input Voltage (Note 2.)	2.3 V ≤ V _{CC} ≤ 2.7 V		0.7	V
		2.7 V ≤ V _{CC} ≤ 3.6 V		0.8	
Vон	HIGH Level Output Voltage	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$	V _{CC} - 0.2		V
		V _{CC} = 2.3 V; I _{OH} = -8 mA	1.8		
		$V_{CC} = 2.7 \text{ V; } I_{OH} = -12 \text{ mA}$	2.2		
		$V_{CC} = 3.0 \text{ V; } I_{OH} = -18 \text{ mA}$	2.4		
		$V_{CC} = 3.0 \text{ V; } I_{OH} = -24 \text{ mA}$	2.2		
VOL	LOW Level Output Voltage	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$		0.2	V
		V _{CC} = 2.3 V; I _{OL} = 8 mA		0.6	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 16 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	
lį	Input Leakage Current	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 0 \text{ V} \le \text{V}_{I} \le 5.5 \text{ V}$		±5.0	μΑ
loz	3-State Output Current	$2.3 \le V_{CC} \le 3.6 \text{ V}; \text{ OV} \le V_{O} \le 5.5 \text{ V};$ V _I = V _{IH} or V _{IL}		±5.0	μА
loff	Power-Off Leakage Current	V _{CC} = 0 V; V _I or V _O = 5.5 V		10	μΑ
ICC	Quiescent Supply Current	$2.3 \le V_{CC} \le 3.6 \text{ V}; \text{ V}_{I} = \text{GND or V}_{CC}$		20	μΑ
		$2.3 \le V_{CC} \le 3.6 \text{ V}$; $3.6 \le V_I \text{ or } V_O \le 5.5 \text{ V}$		±20	μΑ
ΔlCC	Increase in I _{CC} per Input	2.3 ≤ V _{CC} ≤ 3.6 V; V _{IH} = V _{CC} − 0.6 V		500	μΑ

^{2.} These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS $t_R=t_F$ = 2.5ns; R_L = 500 Ω

•				•	Lin	nits			Unit
					T _A = -40°	C to +85°C			
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		$V_{CC} = 2.5 V \pm 0.2 V$		
			C _L =	50 pF	C _L =	50 pF	C _L =	30 pF	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	
tplH tpHL	Propagation Delay Input to Output	1	1.5 1.5	4.5 4.5	1.5 1.5	5.3 5.3	1.5 1.5	5.4 5.4	ns
^t PZH ^t PZL	Output Enable Time to High and Low Level	2	1.5 1.5	5.4 5.4	1.5 1.5	6.0 6.0	1.5 1.5	7.0 7.0	ns
^t PHZ ^t PLZ	Output Disable Time From High and Low Level	2	1.5 1.5	5.3 5.3	1.5 1.5	5.4 5.4	1.5 1.5	6.4 6.4	ns
toshl toslh	Output-to-Output Skew (Note 3.)			1.0 1.0					ns

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toshl) or LOW-to-HIGH (toslh); parameter guaranteed by design.

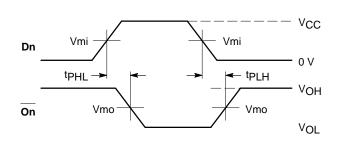
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 4.)	$V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$		0.8 0.6		V V
VOLV	Dynamic LOW Valley Voltage (Note 4.)	$V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ $V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$		-0.8 -0.6		V V

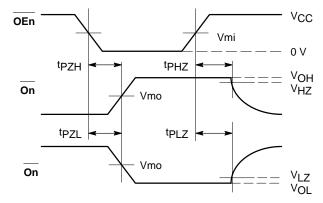
^{4.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	7	pF
COUT	Output Capacitance	$V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	20	pF



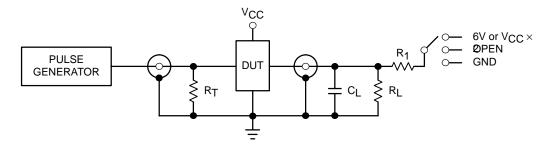
 $\label{eq:waveform 1-PROPAGATION DELAYS} t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5 \text{ ns}$, 10% to 90%; f = 1 MHz; $t_W = 500 \text{ ns}$

	Vcc					
Symbol	3.3 V \pm 0.3 V	2.7 V	2.5 V \pm 0.2 V			
Vmi	1.5 V	1.5 V	V _{CC} /2			
Vmo	1.5 V	1.5 V	V _{CC} /2			
VHZ	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V			
VLZ	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 015 V			

Figure 1. AC Waveforms



TEST	SWITCH
tPLH, tPHL	Open
tPZL, tPLZ	6V at V _{CC} = 3.3 ± 0.3 V 6V at V _{CC} = 2.5 ± 0.2 V
Open Collector/Drain tpLH and tpHL	6V
tPZH, tPHZ	GND

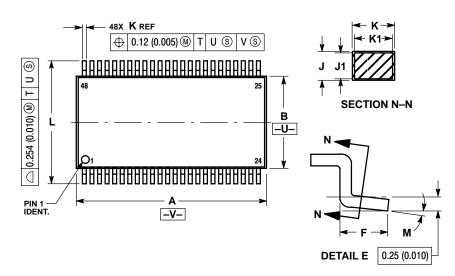
C_L= 50 pF at V_{CC} = 3.3 ± 0.3 V or equivalent (includes jig and probe capacitance) C_L= 30 pF at V_{CC} = 2.5 ± 0.2 V or equivalent (includes jig and probe capacitance) R_L= R₁ = $500~\Omega$ or equivalent (typically $50~\Omega$)

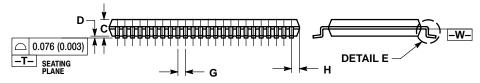
Figure 2. Test Circuit

PACKAGE DIMENSIONS

TSSOP-48 **DT SUFFIX** CASE 1201-01 ISSUE A

SCALE 2:1





- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 6. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	12.40	12.60	0.488	0.496	
В	6.00	6.20	0.236	0.244	
С		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.50	BSC	0.0197 BSC		
Н	0.37		0.015		
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.17	0.27	0.007	0.011	
K1	0.17	0.23	0.007	0.009	
L	7.95	8.25	0.313	0.325	
M	0 °	8°	0 °	8 °	

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